NSN 5961-01-131-4469

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View Online at https://aerobasegroup.com/nsn/5961-01-131-4469 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.700 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 85.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 6.00 amperes source cutoff current and 5.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Using transistor 2n5954, perform all test necessary to meet jantx requirements per mil-s-19500; junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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